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	Application No.	Applicant(s)
Notice of Allowability	10/661,038	HORNG ET AL.
	Examiner	Art Unit
	Rodney G. McDonald	1753
The MAILING DATE of this communication apperall claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI	(OR REMAINS) CLOSED in this ap or other appropriate communication GHTS. This application is subject to	plication. If not included not will be mailed in due course. THIS
1. $igspace$ This communication is responsive to <u>Amendment filed 10-</u>	<u>10-06</u> .	
2. 🗵 The allowed claim(s) is/are <u>1-12</u> .	•	
 Acknowledgment is made of a claim for foreign priority unapplication. All b) Some* c) None of the: Certified copies of the priority documents have Certified copies of the priority documents have Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE" on the documents have 	been received. been received in Application No cuments have been received in this of this communication to file a reply	national stage application from the
THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 4. A SUBSTITUTE OATH OR DECLARATION must be submit	itted. Note the attached EXAMINER	
INFORMAL PATENT APPLICATION (PTO-152) which give	es reason(s) why the oath or declara	ation is deficient.
CORRECTED DRAWINGS (as "replacement sheets") mus		
(a) including changes required by the Notice of Draftspers	-	948) attached
1) hereto or 2) to Paper No./Mail Date		
(b) including changes required by the attached Examiner's Paper No./Mail Date		
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in the		
 DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT I 		
Attachment(s) 1. ☐ Notice of References Cited (PTO-892)	5. ☐ Notice of Informal P	Patent Application
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Summary Paper No./Mail Dat	
3. Information Disclosure Statements (PTO/SB/08), Paper No./Mail Date	7. Examiner's Amendr	ment/Comment
4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material	8. X Examiner's Stateme	ent of Reasons for Allowance
5. Distinguish material	9.	·
	·	Rodney 6, McDonald RODNEY G. MCDONALD ROBINARY EYADDIDER

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REASONS FOR ALLOWANCE

The following is an examiner's statement of reasons for allowance:

Claims 1-12 are indicated as being allowable over the prior art of record because the prior art of record does not teach a method for forming a spin valve GMR sensor element with layers having sub-atomic monolayers of oxygen absorbed on the surfaces thereof comprising providing, in a sputtering chamber having a base pressure, a substrate; forming on the substrate, using an Ar/O₂ mixture as a sputtering gas, a seed layer; forming, using said sputtering gas, an antiferromagnetic pinning layer on the seed layer; forming, using the sputtering gas, a synthetic antiferromagnetic (SyAF) pinned layer formed on the pinning layer; forming, using only Ar as a sputtering gas, a Cu spacer layer on the SyAF layer, the surface of the spacer layer not contacting the SyAF layer then being treated with O₂ to form an oxygen surfactant layer (OSL); forming, again using the Ar/O₂ mixture, a ferromagnetic free layer on the OSL of the treated spacer layer; forming, using only Ar as a sputtering gas, a Ru capping layer on the ferromagnetic free layer, then forming an OSL layer on the Ru layer; forming, using the Ar/O₂ mixture as a sputtering gas, a Ta capping layer on the Ru capping layer.

The prior art of record teach spin valve sensors but fails to teach forming the spin valve GMR sensor element as claimed by applicant including the specifics for depositing the layers in the sputtering chamber. The benefit of controlling the process conditions during the formation of the layers is that it will produce a magnetic head with high densities, improved exchange coupling properties and greater thermal stability.

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Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Rodney G. McDonald whose telephone number is 571-272-1340. The examiner can normally be reached on M- Th with Every other Friday off.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nam X. Nguyen can be reached on 571-272-1342. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Rodney G. McDonald Primary Examiner Art Unit 1753

RM December 11, 2006